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Massachusetts Institute of Technology Department of Electrical Engineering and Computer Science,	2012.09
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XPERIENCES	
Carnegie Mellon University Department of Electrical and Computer Engineering	2019.00 – present
Argonne National Laboratory	2018.06 - 2019.07
Massachusetts Institute of Technology Microsystems Technology Laboratories	2017.06 – 2018.06
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DS	
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SELECTED PUBLICATIONS (Google Scholar Citation: 2555; since 2017: 2224; h-index: 18; i-10 index: 19)

MIT Global Fellowship (Massachusetts Institute of Technology)

Guo Moruo Scholarship (Highest honor for undergrads in USTC)

Chinese National Scholarship (twice)

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## **ACADEMIC SERVICES**

Associate Guest Editor, for journal Thin Solid Films, Frontiers in Materials

**Peer Review,** for academic journals, including Nature Nanotechnology, Physical Review B, IEEE Electron Device Letters, Nature Electronics, Advanced Optical Materials, npj Computational Materials, ACS Applied Materials & Interfaces, 2D Materials, and Physical Review Applied, IEEE Transactions on Nanotechnology, physica status solidi (b), Applied Physics A, Nanotechnology, Thin Solid Films, and Journal of Physics D: Applied Physics

Organization Committee of MIT Microsystems Annual Research Conference (MARC)

**Organization Committee** of 2022 Materials Research Society (MRS) Fall Meeting, Symposium EQ06, Two-Dimensional (2D) van der Waals Materials - Quantum Properties and Electronic and Photonic Devices, Boston, Massachusetts, November 27 - December 2, 2022

#### **TEACHING**

## **Undergraduate Course:**

18-220: Electronic Devices and Analog Circuits (Units: 12), Department of Electrical and Computer Engineering, Carnegie Mellon University

## **Graduate Course:**

18-819D: Special Topics in Applied Physics: Memory Devices and Technology (Units: 12), Department of Electrical and Computer Engineering, Carnegie Mellon University